

PROTECTION PRODUCTS
Absolute Maximum Rating

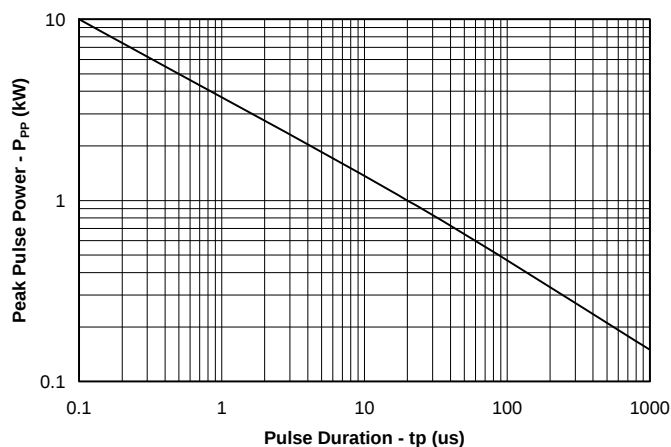
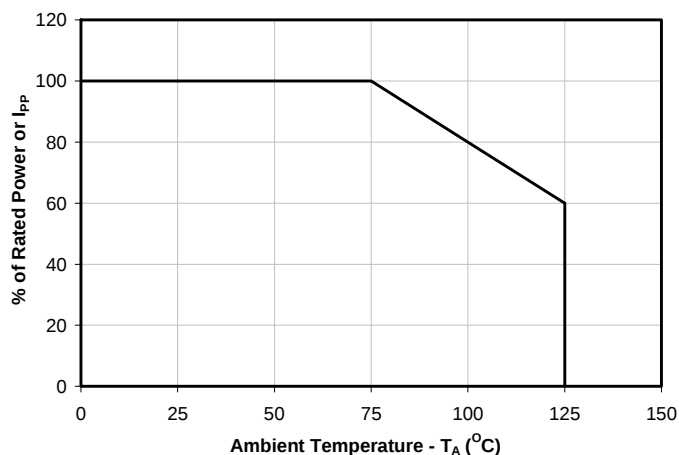
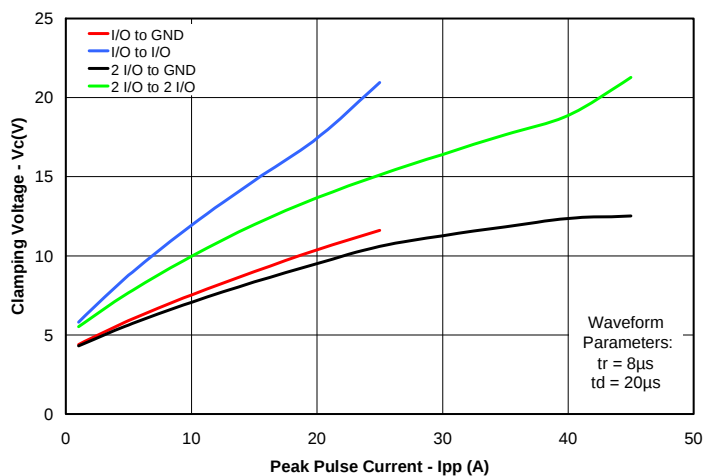
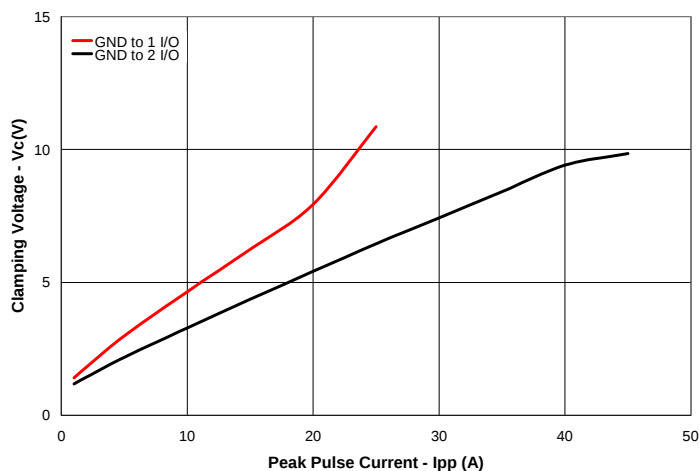
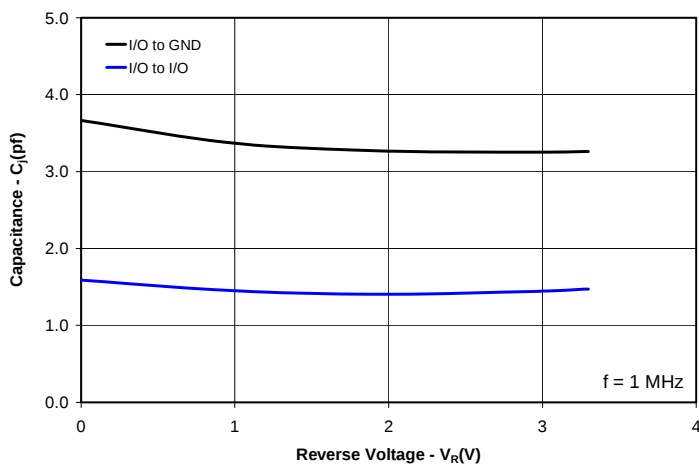
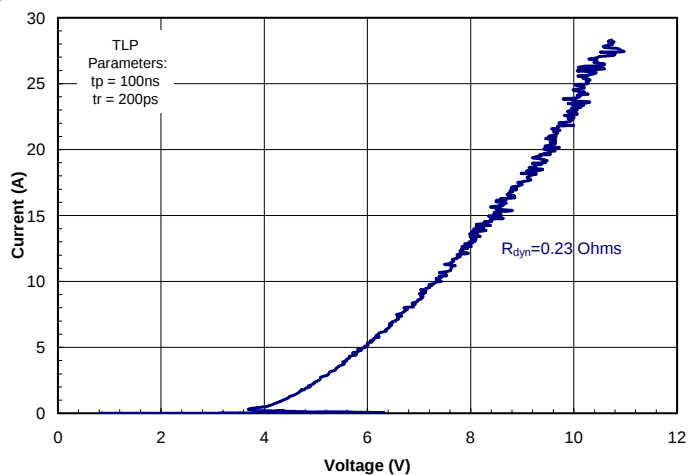
Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$) ¹	P_{pk}	1000	Watts
Peak Pulse Current ($t_p = 8/20\mu s$) ¹	I_{pp}	40	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V_{ESD}	+/-30 +/-30	kV
Operating Temperature	T_j	-40 to +125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

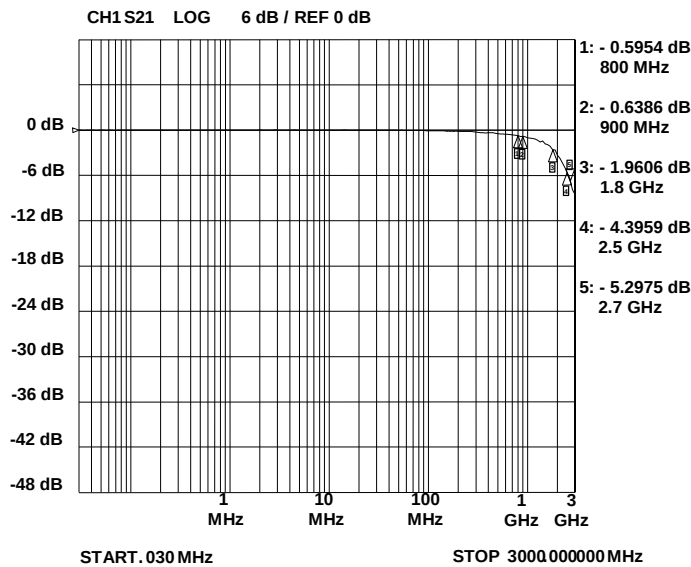
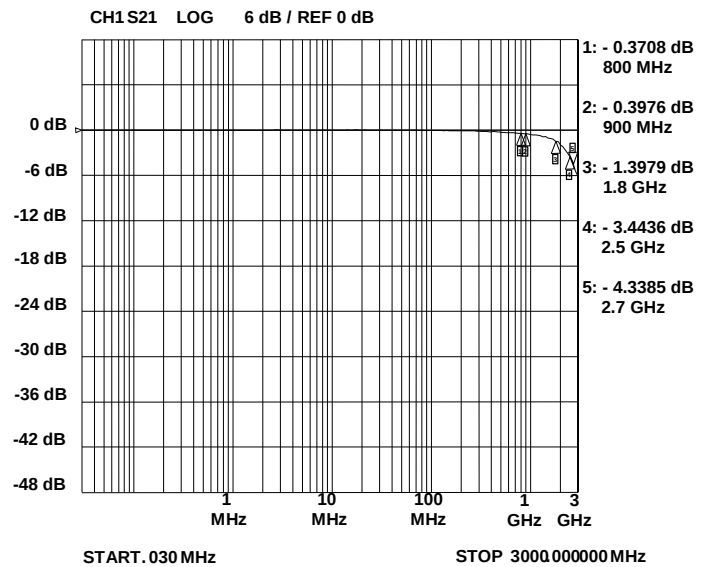
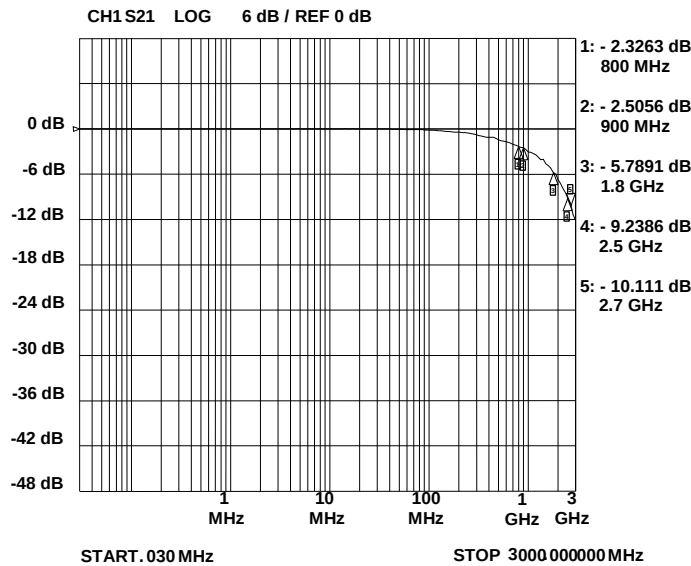
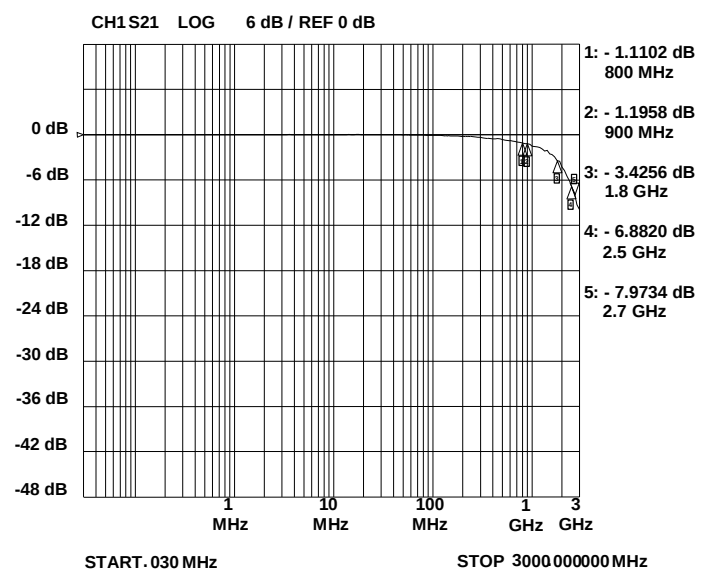
Electrical Characteristics (T=25°C unless otherwise specified)

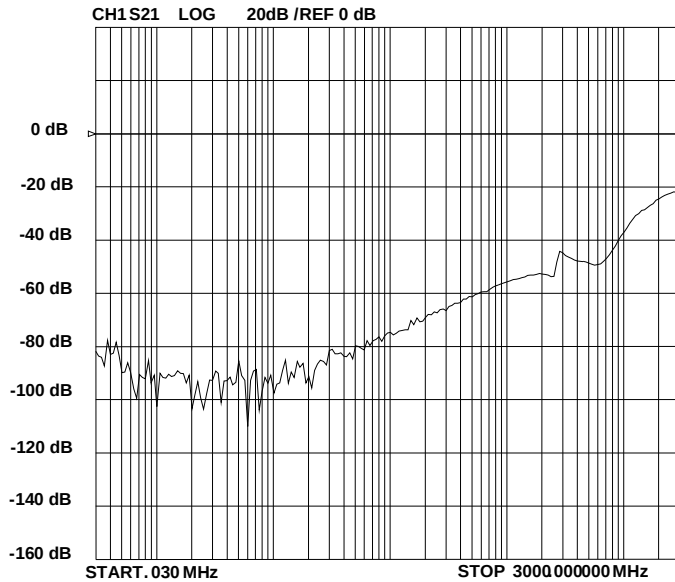
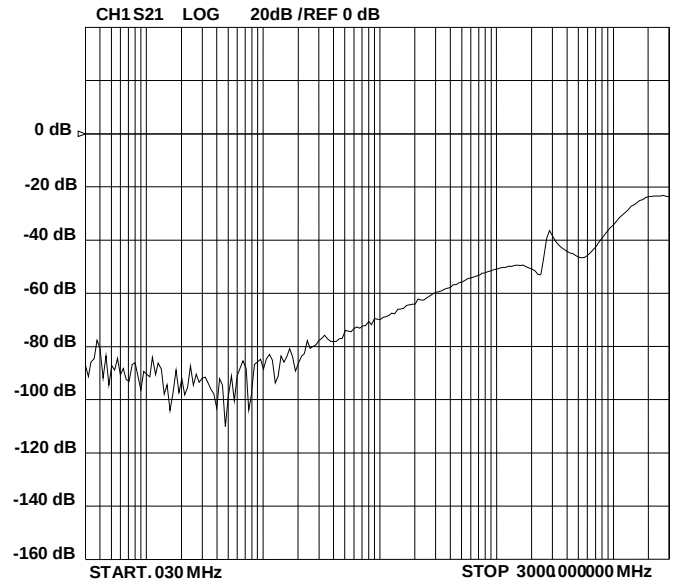
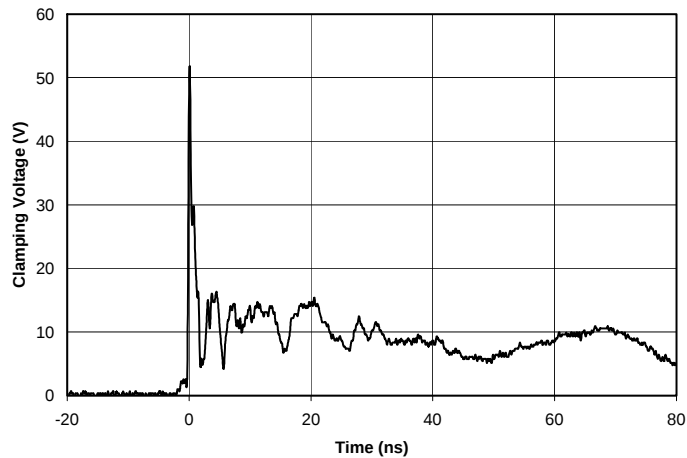
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				3.3	V
Punch-Through Voltage	V_{PT}	$I_{PT} = 2\mu A$	3.5			V
Snap-Back Voltage	V_{SB}	$I_{SB} = 50mA$	2.8			V
Reverse Leakage Current	I_R	$V_{RWM} = 3.3V, T=25^\circ C$			0.5	μA
Reverse Leakage Current	I_R	$V_{RWM} = 3.3V, T=125^\circ C$			1	μA
Clamping Voltage ²	V_C	$I_{pp} = 1A, t_p = 8/20\mu s$ Any I/O to Ground			5.5	V
Clamping Voltage ²	V_C	$I_{pp} = 10A, t_p = 8/20\mu s$ Any 1 I/O to Ground			10.5	V
Clamping Voltage ²	V_C	$I_{pp} = 25A, t_p = 8/20\mu s$ Any I/O to Ground			18	V
Clamping Voltage ^{1,2}	V_C	$I_{pp} = 40A, t_p = 8/20\mu s$ Line-to-Line, two I/O pins connected together on each line (Note 1)			25	V
Junction Capacitance ²	C_j	$V_R = 0V, f = 1MHz$ Any I/O to Ground		3.6	5	pF
		$V_R = 0V, f = 1MHz$ Between I/O pins		1.7		pF

Notes:

- 1) Ratings with 2 pins connected together per the recommended configuration (ie pin 1 connected to pin 10, pin 2 connected to pin 9, pin 4 connected to pin 7, and pin 5 connected to pin 6).
- 2) Guaranteed by design (not production tested)

PROTECTION PRODUCTS
Typical Characteristics
Non-Repetitive Peak Pulse Power vs. Pulse Time

Power Derating Curve

Clamping Voltage vs. Peak Pulse Current

Forward Clamping Voltage vs. Peak Pulse Current

Capacitance vs. Reverse Voltage

Typical TLP Characteristic


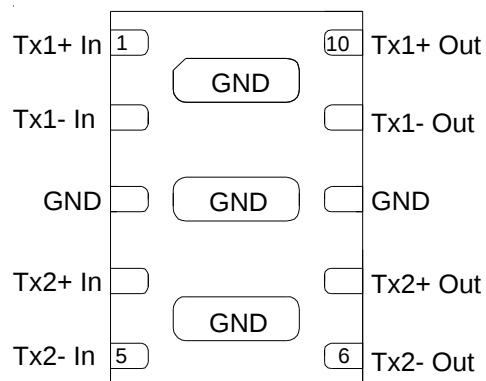
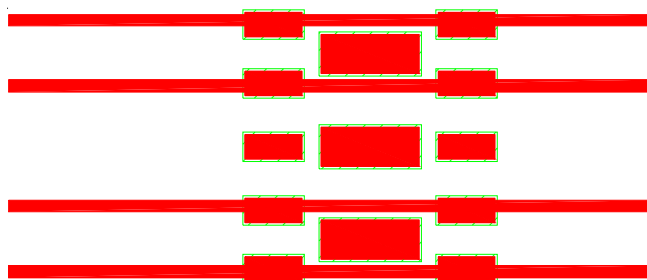
PROTECTION PRODUCTS
Typical Characteristics (Con't)
Insertion Loss S21 (I/O to Gnd)

Insertion Loss S21 (I/O to I/O)

Insertion Loss S21 (2 I/O to Gnd)

Insertion Loss S21 (2 I/O to 2 I/O)


PROTECTION PRODUCTS
Typical Characteristics (Con't)
Analog Crosstalk (I/O to GND)

Analog Crosstalk (I/O to I/O)

**ESD Clamping - I/O to Gnd
(8kV Contact per IEC 61000-4-2)**


PROTECTION PRODUCTS
Applications Information
Device Connection Options for Protection of Four High-Speed Data Lines

This device is designed to protect four high-speed data lines (two line pairs). It has been optimized for use on Ethernet interfaces where large magnitude lightning and ESD surges are expected. The RClamp3374N is constructed using Semtech's proprietary EPD process technology. The EPD process provides low stand-off (turn-on) voltages with significant reductions while maintaining good clamping characteristics and high surge capability. They feature a true operating voltage of 3.3 volts. Each I/O pin pair features a low capacitance steering diode bridge that is designed to route harmful surge current into the internal low voltage TVS diode. Each data pair is rated to withstand 1000 Watts of surge power (8/20us impulse waveform). When placed on the PHY side of the magnetics, it can be used to meet the requirements of Telcordia GR-1089, K.20, K.21, and other high energy surge standards.

The RClamp3374N is designed with a flow through pin configuration for easy layout. In a GbE application, TX+ and TX- lines would enter at pins 1, 2, 4, and 5 and exit at pins 10, 9, 7, and 6 respectively. The traces should be unbroken and run under the device as shown. Pins 3 and 8 are electrically connected to the three center ground tabs. In a typical Ethernet application, these pins as well as the tabs should be left floating (i.e. not connected to ground).

Pin Configuration

Layout Example


PROTECTION PRODUCTS

Applications Information

Gigabit Ethernet Protection Solutions

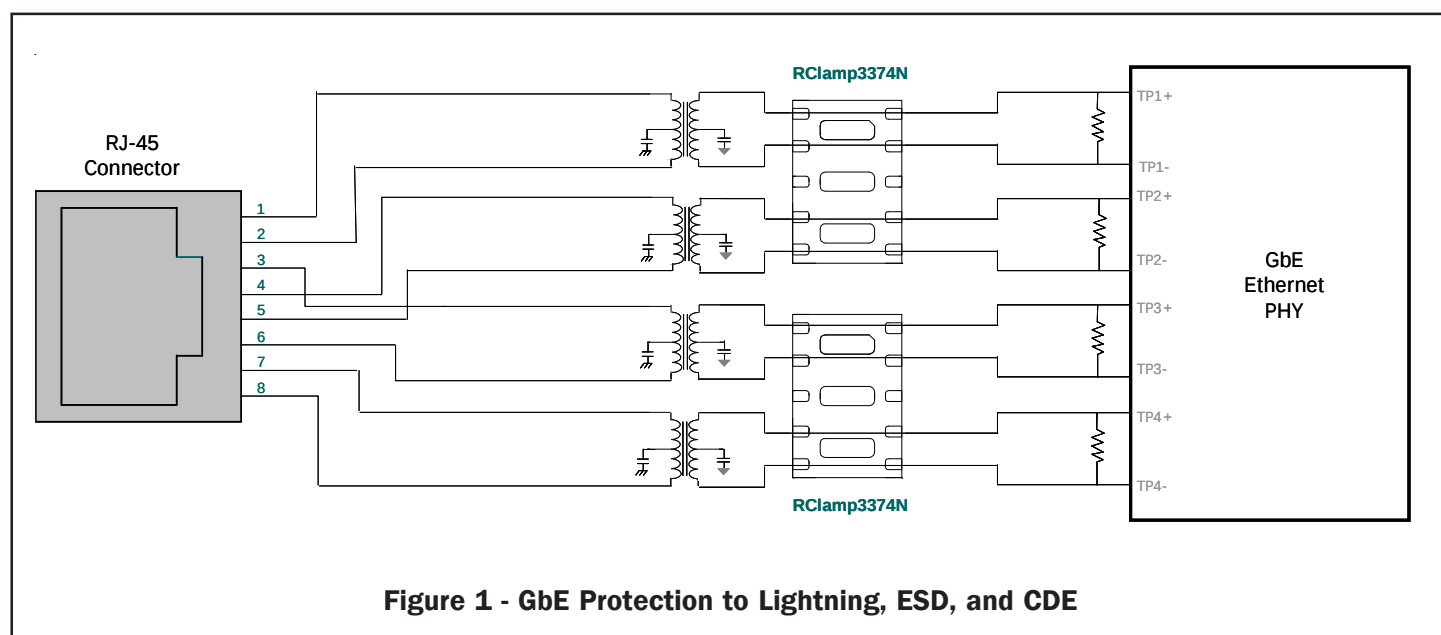
Ethernet systems with connections external to the building are subject to high-level transient threats. This type of equipment may even be required to meet the surge immunity requirements of Telcordia GR-1089. Reliable protection of the Ethernet transceiver requires a device that can absorb the expected transient energy, clamp the incoming surge to a safe level, and yet remain transparent to the system under normal operation. The RClamp3374N has been designed to meet these demanding requirements.

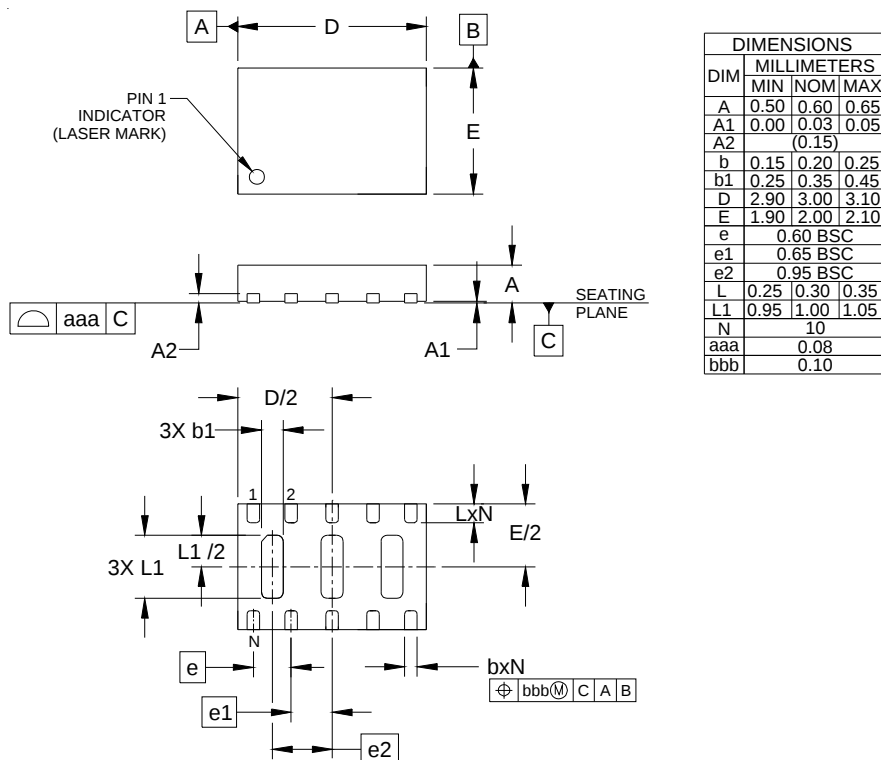
Transient Protection

When designing Ethernet protection, the entire system must be considered. An Ethernet port includes interface magnetics in the form of transformers and common mode chokes. Transformers and chokes can be discrete components, but integrated solutions that include the RJ-45 connector, resistors, capacitors, and protection are also available. In either case, the transformer will provide a high level of common mode isolation to external voltages, but no protection for metallic (line-to-line) surges. During a metallic transient event, current will flow into one line, through the transformer and back to the source. As the current flows, it charges the windings of the transformer on the line side. Once the surge is removed, the windings on the line side will stop charging and will transfer its stored energy to the IC side where the PHY IC is located. The magnitude and

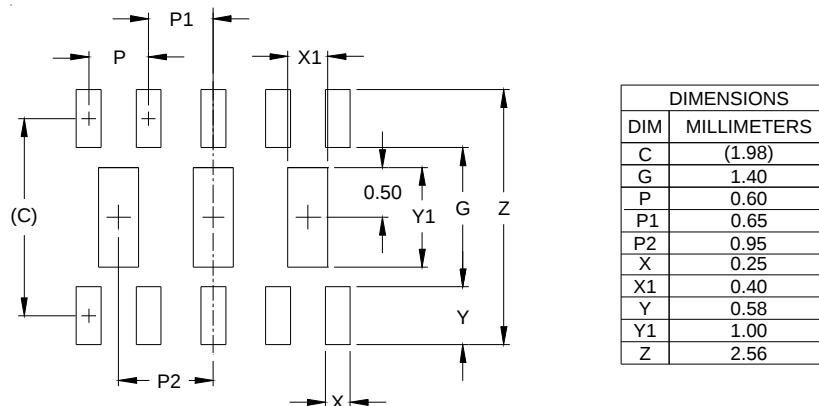
duration of the surge is attenuated by the inductance of the magnetics. The amount of attenuation will vary by vendor and configuration of the magnetics. It is this transferred energy that must be clamped by the protection circuitry.

A typical protection scheme which utilizes the RClamp3374N is shown in Figure 1. One device is placed across two line pairs and is located on the PHY side of the transformer as close to the magnetics as possible. This is done to minimize parasitic inductance and improve clamping performance. In this design, the isolation voltage of the transformer is relied upon to suppress common mode lightning surges. High voltage capacitors and resistors are commonly utilized from the center tap to ground to aid in transient protection. Metallic surges will be transferred in some form to the PHY side and clamped by the RClamp3374N. The RClamp3374N will turn on when the voltage across it exceeds the punch-through voltage of the device. Low voltage turn on is important since many PHY chips have integrated ESD protection structures. These structures are for protection of the device during manufacture and are not designed to handle large amounts of energy. Should they turn on before the external protection, they can be damaged resulting in failure of the PHY chip.

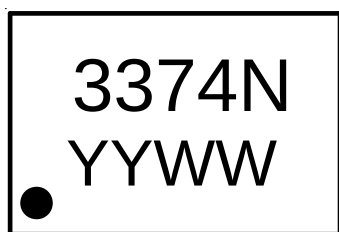


PROTECTION PRODUCTS
Outline Drawing - SLP3020N10

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).

Land Pattern - SLP3020N10

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.
CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

PROTECTION PRODUCTS
Marking Codes


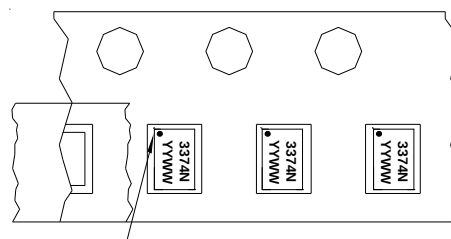
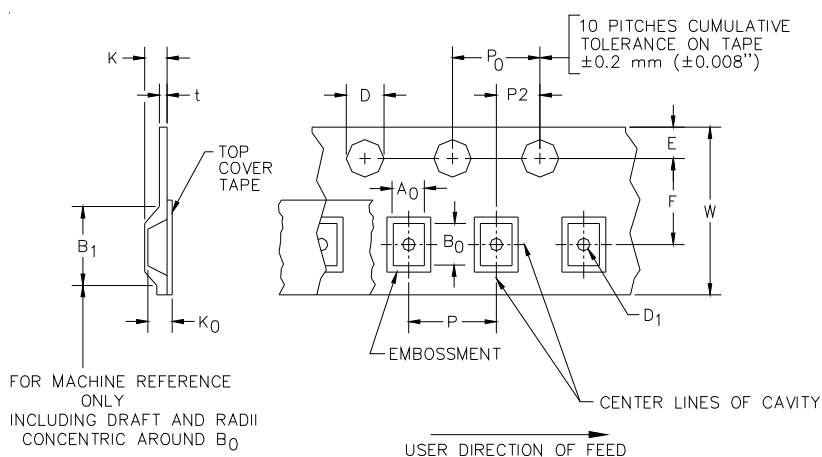
1

YYWW = Date Code

Ordering Information

Part Number	Working Voltage	Qty per Reel	Reel Size
RClamp3374N.TCT	3.3 Volts	3,000	7 Inch

RailClamp and RClamp are trademarks of Semtech Corporation

Carrier Tape Specification


Pin 1 Location (Towards Sprocket Holes)

→
User Direction of feed

Device Orientation in Tape

A0	B0	K0
2.24 +/-0.05 mm	3.23 +/-0.05 mm	0.93 +/-0.05 mm

Tape Width	B, (Max)	D	D1	E	F	K (MAX)	P	P0	P2	T(MAX)	W
8 mm	4.2 mm	1.5 + 0.1 mm - 0.0 mm)	0.5 mm ±0.05	1.750±.10 mm	3.5±0.05 mm	2.4 mm	4.0±0.1 mm	4.0±0.1 mm	2.0±0.05 mm	0.4 mm	8.0 mm + 0.3 mm - 0.1 mm

Contact Information

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